NSN 5961-01-332-8088

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-332-8088 **Overall Length:** Between 0.072 inches and 0.078 inches **Overall Height:** Between 0.030 inches and 0.040 inches **Overall Width:** Between 0.037 inches and 0.043 inches **Function For Which Designed:** Zener diode **Mounting Method:** Terminal **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 5.88 breakdown voltage, dc **Current Rating Per Characteristic:** 70.00 milliamperes source cutoff current horsepower metric **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Precious Material And Location:** Eutectic die bonds surfaces terminals and land areas surfaces gold **Precious Material:**

| Gold |
|-----------------------------|
| Terminal Type And Quantity: |
| 4 bonding pad |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| No |
| Fiig: |
| A110a0 |
| |
| |
| |